



FOR IMMEDIATE RELEASE

Diodes, Inc. Releases New Medium Power Bipolar Junction Transistors

Dallas, Texas, November 29, 2007 – Diodes Incorporated (Nasdaq: DIOD), a leading global manufacturer and supplier of high-quality application specific standard products within the broad discrete and analog semiconductor markets, today announced the release of 21 medium-power bipolar junction transistors in its SOT89-3L package. These new devices are suitable for a wide range of high volume applications, which include switching and linear amplification, pass elements for discrete linear voltage regulators, MOSFET drivers for switching regulators, supply-line switches, medium-powered load switches, and power management circuits.

The bipolar junction transistors feature high collector current ratings and low collector-to-emitter saturation voltages, making these components well suited for a wide range of end-user products that are in high demand today, such as computers, portable consumer electronics, LED lighting, networking and telecommunications, set-top boxes and power supplies.

“With the release of these devices, we are continuing the expansion of our product offerings beyond small signal into medium-power devices with higher current and power,” commented Mark King, Sr. VP of Sales and Marketing of Diodes, Inc. “The SOT89-3L medium-power bipolar transistor line is a follow-on to our highly successful SOT-223 medium-power transistors released in August. The expansion of our medium-power transistor product portfolio creates the opportunity for new revenue streams and helps improve Diodes’ position as a complete analog and discrete solution provider to our customers.”

The introduction of these 21 bipolar junction transistor components exemplifies Diodes’ flexibility, as it continues its expansion into the medium-power bipolar transistor market. These new products are offered in a voltage range of 20V-300V and a current range of 0.2A-5A.

The part numbers released include: 2DB1132, 2DD1664, 2DB1188, 2DD1766, 2DD2150, 2DB1386, DCX51, DCX52, DCX53, DCX54, DCX55, DCX56, DCX68, DCX69, DXT3904, DXT3906, DXT2222A, DXT2907A, DXTA42, DXTA92, and DXT3150.

These components are produced at Diodes’ state-of-the-art manufacturing facilities located in Shanghai, China, and all are fully RoHS compliant, including Green Molding compound.

About Diodes Incorporated

Diodes Incorporated (Nasdaq: DIOD) an S&P SmallCap 600 Index company, is a leading global manufacturer and supplier of high-quality application specific standard products within the broad discrete and analog semiconductor markets, serving the consumer electronics, computing, communications, industrial and automotive markets. Diodes’ products include diodes, rectifiers, transistors, MOSFETs, protection devices, functional specific arrays, power management devices including DC-DC switching and linear voltage regulators, amplifiers and comparators, and Hall-effect sensors. The Company has its corporate offices in Dallas, Texas, with a sales, marketing, engineering and logistics office in Southern California; design centers in Dallas, San Jose and Taipei; a wafer fabrication facility in Missouri; two manufacturing facilities in Shanghai; a fabless IC plant in Hsinchu Science Park, Taiwan; engineering, sales, warehouse and logistics offices in Taipei and Hong Kong, and sales and support offices throughout the world. With its recent asset acquisition of APD Semiconductor, a privately held U.S.-based fabless

semiconductor company, Diodes acquired proprietary SBR® technology. Diodes, Inc.'s product focus is on high-growth end-user equipment markets such as TV/Satellite set-top boxes, portable DVD players, datacom devices, ADSL modems, power supplies, medical devices, wireless notebooks, flat panel displays, digital cameras, mobile handsets, DC to DC conversion, wireless 802.11 LAN access points, brushless DC motor fans, and automotive applications. For further information, including SEC filings, visit the Company's website at <http://www.diodes.com>.

Safe Harbor Statement Under the Private Securities Litigation Reform Act of 1995: Any statements set forth above that are not historical facts are forward-looking statements that involve risks and uncertainties that could cause actual results to differ materially from those in the forward-looking statements. Potential risks and uncertainties include, but are not limited to, such factors as the introduction and market reception to new product announcements, fluctuations in product demand, the introduction of new products, the Company's ability to maintain customer and vendor relationships, technological advancements, impact of competitive products and pricing, growth in targeted markets, successful integration of acquired companies and/or assets, the Company's ability to successfully make additional acquisitions, risks of foreign operations, availability of tax credits, and other information detailed from time to time in the Company's filings with the United States Securities and Exchange Commission.

Source: Diodes Incorporated

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Recent news releases, annual reports, and SEC filings are available at the Company's website:
<http://www.diodes.com>. Written requests may be sent directly to the Company, or they may be e-mailed to:
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